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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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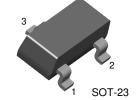




KSC3123

Mixer for UHF TV Tuner

- G_{CE} =23dB G_{RE} =0.4pF



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	20	V
V_{EBO}	Emitter-Base Voltage	3	V
I _C	Collector Current	50	mA
I _B	Base Current	25	mA
P _C	Collector Power Dissipation	150	mW
TJ	Junction Temperature	1500	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

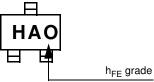
Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =1mA, I _B =0	20			V
I _{CBO}	Collector Cut-off Current	V_{CB} =25V, I_{E} =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB}=3V$, $I_{C}=0$			1	μΑ
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =5mA	60		240	
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =5mA	900	1400		MHz
C _{RE}	Reverse Transfer Capacitance	V _{CB} =10V, I _E =0, f=1MHz		0.4	0.5	pF
G _{CE}	Conversion Gain	V _{CC} =12V, f=200MHz f _L =260MHz	20	23		dB
NF	Output Capacitance	V _{CE} =12V, f=200MHz, f _L =260MHz		3.8	5.5	dB

h_{FE} Classification

Classification	R	0	Y
h _{EE}	60 ~ 120	90 ~ 180	120 ~ 240

Marking



Typical Characteristics

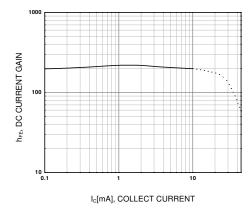
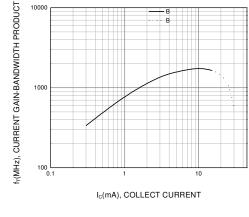


Figure 1. DC current Gain



10000

Figure 2. Current Gain Bandwidth Product

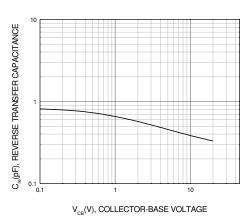


Figure 3. C_{RE} - V_{CB}

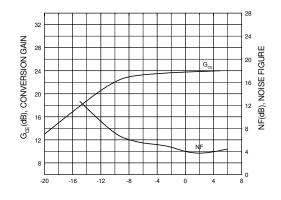


Figure 4. G_{CE}, NF-

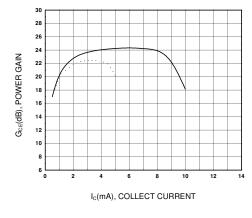


Figure 5. G_{CE}-I_C

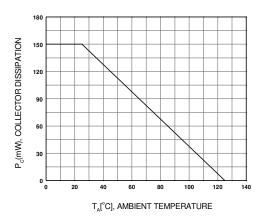
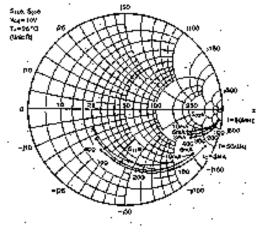


Figure 6. P_C-T_A

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Typical Characteristics (Continued)



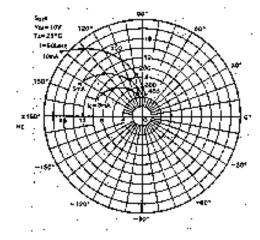


Figure 7.

Figure 8.

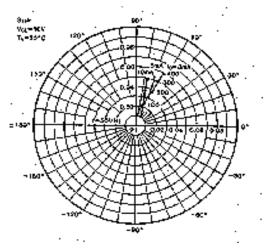
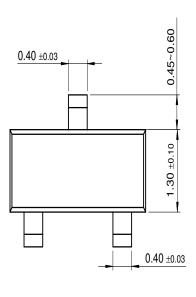
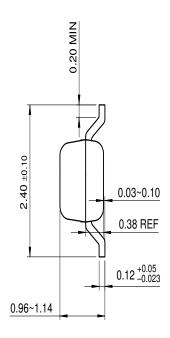


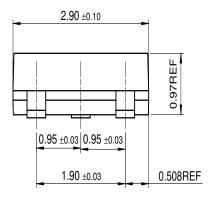
Figure 9.

Package Dimensions

SOT-23







Dimensions in Millimeters

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Rev. I1

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